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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Low-Voltage CMOS Unbuffered Hex Inverter

With 5 V-Tolerant Inputs

The MC74LCXU04 is a high performance unbuffered hex inverter operating from a 2.3 to 3.6 V supply. (High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance.) A $V_{\rm I}$ specification of 5.5 V allows MC74LCXU04 inputs to be safely driven from 5 V devices.

Features

- Designed for 2.3 to 3.6 V V_{CC} Operation
- 5 V Tolerant Inputs Interface Capability With 5 V TTL Logic
- LVTTL Compatible
- LVCMOS Compatible
- Near Zero Static Supply Current (10 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance:
 - ♦ Human Body Model >2000 V
 - ♦ Machine Model >200 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



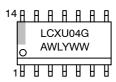
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http://onsemi.com

MARKING DIAGRAMS



SOIC-14 D SUFFIX CASE 751A





TSSOP-14 DT SUFFIX CASE 948G



A = Assembly Location

L, WL = Wafer Lot Y, YY = Year W, WW = Work Week G or • = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

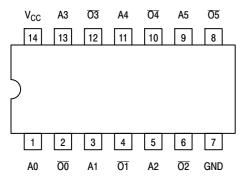


Figure 1. Pinout: 14-Lead (Top View)

PIN NAMES

| Pins | Function | |
|------|-------------|--|
| An | Data Inputs | |
| On | Outputs | |

TRUTH TABLE

| An | On |
|----|----|
| L | Н |
| Н | L |

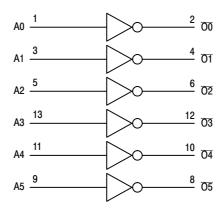


Figure 2. Logic Diagram

MAXIMUM RATINGS

| Symbol | Parameter | Value | Condition | Units |
|------------------|----------------------------------|---------------------------------|---------------------------------------|-------|
| V _{CC} | DC Supply Voltage | -0.5 to +7.0 | | V |
| VI | DC Input Voltage | $-0.5 \le V_1 \le +7.0$ | | ٧ |
| Vo | DC Output Voltage | $-0.5 \le V_O \le V_{CC} + 0.5$ | Output in HIGH or LOW State. (Note 1) | ٧ |
| I _{IK} | DC Input Diode Current | -50 | V _I < GND | mA |
| lok | DC Output Diode Current | -50 | V _O < GND | mA |
| | | +50 | V _O > V _{CC} | mA |
| Io | DC Output Source/Sink Current | ±50 | | mA |
| I _{CC} | DC Supply Current Per Supply Pin | ±100 | | mA |
| I _{GND} | DC Ground Current Per Ground Pin | ±100 | | mA |
| T _{STG} | Storage Temperature Range | -65 to +150 | | °C |
| MSL | Moisture Sensitivity | | Level 1 | |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Тур | Max | Units |
|-----------------|--|------------|----------------------|------------------|-------|
| V _{CC} | Supply Voltage Operating Data Retention Only | 2.0 1.5 | 2.5, 3.3 2.5, 3.3 | 3.6 3.6 | V |
| VI | Input Voltage | 0 | | 5.5 | V |
| Vo | Output Voltage (HIGH or LOW State) | 0 | | V _{CC} | ٧ |
| I _{OH} | $ \begin{array}{l} \mbox{HIGH Level Output Current} \\ \mbox{V}_{CC} = 3.0 \ \mbox{V} - 3.6 \ \mbox{V} \\ \mbox{V}_{CC} = 2.7 \ \mbox{V} - 3.0 \ \mbox{V} \\ \mbox{V}_{CC} = 2.3 \ \mbox{V} - 2.7 \ \mbox{V} \end{array} $ | | | -18 -12 -8 | mA |
| l _{OL} | LOW Level Output Current $V_{CC} = 3.0 \text{ V} - 3.6 \text{ V}$ $V_{CC} = 2.7 \text{ V} - 3.0 \text{ V}$ $V_{CC} = 2.3 \text{ V} - 2.7 \text{ V}$ | | | +16 +12 +8 | mA |
| T _A | Operating Free-Air Temperature | -40 | | +85 | °C |
| Δt/ΔV | Input Transition Rise or Fall Rate, V_{IN} from 0.8 V to 2.0 V, V_{CC} = 3.0 V | 0 | | 10 | ns/V |

DC ELECTRICAL CHARACTERISTICS

| | Characteristic | | T _A = −40°C | | |
|---------------------------|---------------------------------------|---|------------------------|------|-------|
| Symbol | | Condition | Min | Max | Units |
| V _{IH} | HIGH Level Input Voltage (Note 2) | V _{CC} = 2.3 V | 1.7 | | ٧ |
| | | V _{CC} = 2.7 V | 2.1 | | |
| | | V _{CC} = 3.0 V | 2.2 | | |
| | | V _{CC} = 3.6 V | 2.7 | | |
| V _{IL} | LOW Level Input Voltage (Note 2) | V _{CC} = 2.3 V | | 0.55 | V |
| | | V _{CC} = 2.7 V | | 0.55 | |
| | | V _{CC} = 3.0 V | | 0.55 | |
| | | V _{CC} = 3.6 V | | 0.55 | |
| V _{OH} HIGH Leve | HIGH Level Output Voltage | $2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{ I}_{OL} = 100 \mu\text{A}$ | V _{CC} - 0.2 | | V |
| | | V _{CC} = 2.3 V; I _{OH} = -8 mA | 1.8 | | |
| | | $V_{CC} = 2.7 \text{ V}; I_{OH} = -12 \text{ mA}$ | 2.2 | | |
| | | $V_{CC} = 3.0 \text{ V}; I_{OH} = -18 \text{ mA}$ | 2.4 | | |
| V _{OL} | LOW Level Output Voltage | $2.3~V \le V_{CC} \le 3.6~V;~I_{OL} = 100~\mu A$ | | 0.2 | V |
| | | V _{CC} = 2.3 V; I _{OL} = 8 mA | | 0.6 | |
| | | V _{CC} = 2.7 V; I _{OL} = 12 mA | | 0.4 | |
| | | V _{CC} = 3.0 V; I _{OL} = 16 mA | | 0.5 | |
| I _{OFF} | Power Off Leakage Current | V _{CC} = 0, V _{IN} = 5.5 V or V _{OUT} = 5.5 V | | 10 | μΑ |
| I _{IN} | Input Leakage Current | V _{CC} = 3.6 V, V _{IN} = 5.5 V or GND | | ±5 | μΑ |
| I _{CC} | Quiescent Supply Current | V _{CC} = 3.6 V, V _{IN} = 5.5 V or GND | | 10 | μΑ |
| ΔI_{CC} | Increase in I _{CC} per Input | $2.3 \le V_{CC} \le 3.6 \text{ V}; V_{IH} = V_{CC} - 0.6 \text{ V}$ | | 500 | μΑ |

^{2.} These values of V_I are used to test DC electrical characteristics only.

AC CHARACTERISTICS ($t_R = t_F = 2.5 \text{ ns}$; $R_L = 500 \Omega$) (Note 3)

| | | | Limits $T_{A} = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ | | | | | | |
|--------------------------------------|--------------------------------------|----------|--|---------------------------------|------------------------|------------|------------------------|------------|-------|
| | | | V _{CC} = 3.3 | V _{CC} = 3.3 V ± 0.3 V | | | V _{CC} = 2.5 | V ± 0.2 V | |
| | | | C _L = 50 pF | | C _L = 50 pF | | C _L = 30 pF | | |
| Symbol | Parameter | Waveform | Min | Max | Min | Max | Min | Max | Units |
| t _{PLH} t _{PHL} | Propagation Delay Input to Output | 1 | 1.0 1.0 | 3.6 3.6 | 1.0 1.0 | 4.5 4.5 | 1.0 1.0 | 4.3 4.3 | ns |
| toshl toslh | Output-to-Output Skew (Note 4) | | | 1.0 1.0 | | | | | ns |

^{3.} These AC parameters are preliminary and may be modified.

DYNAMIC SWITCHING CHARACTERISTICS

| | | | T _A = +25°C | | | |
|------------------|--------------------------------------|--|------------------------|--------------|-----|-------|
| Symbol | Characteristic | Condition | Min | Тур | Max | Units |
| V _{OLP} | Dynamic LOW Peak Voltage (Note 5) | $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ $V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ | | 0.8 0.6 | | V |
| V _{OLV} | Dynamic LOW Valley Voltage (Note 5) | $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ $V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ | | -0.8 -0.6 | | V |

^{5.} Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

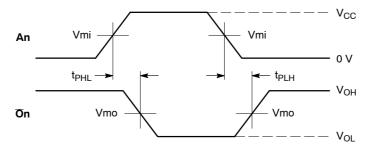
| Symbol | Parameter | Parameter Condition | | Units |
|------------------|-------------------------------|---|----|-------|
| C _{IN} | Input Capacitance | V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC} | 7 | pF |
| C _{OUT} | Output Capacitance | V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC} | 8 | pF |
| C _{PD} | Power Dissipation Capacitance | 10 MHz, V_{CC} = 3.3 V, V_I = 0 V or V_{CC} | 25 | pF |

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|-----------------------|-----------------------|
| MC74LCXU04DG | SOIC-14 (Pb-Free) | 55 Units / Rail |
| MC74LCXU04DR2G | SOIC-14 (Pb-Free) | 2500 Tape & Reel |
| MC74LCXU04DTG | TSSOP-14 (Pb-Free) | 96 Units / Rail |
| MC74LCXU04DTR2G | TSSOP-14 (Pb-Free) | 2500 Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device.
 The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

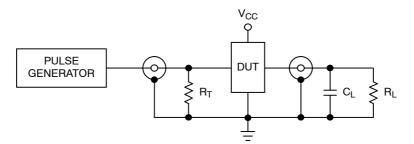


PROPAGATION DELAYS

 $t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$

| | V _{CC} | | | |
|--------|-------------------|-------|--------------------|--|
| Symbol | 3.3 V \pm 0.3 V | 2.7 V | 2.5 V \pm 0.2 V | |
| Vmi | 1.5 V | 1.5 V | V _{CC} /2 | |
| Vmo | 1.5 V | 1.5 V | V _{CC} /2 | |

Figure 3. AC Waveforms

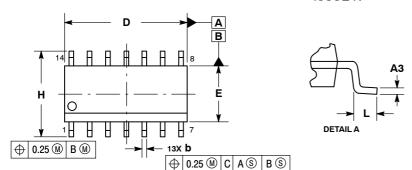


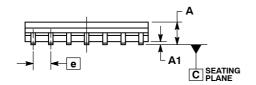
 $C_L=50$ pF at $V_{CC}=3.3\pm0.3$ V or equivalent (includes jig and probe capacitance) $C_L=30$ pF at $V_{CC}=2.5\pm0.2$ V or equivalent (includes jig and probe capacitance) $R_L=R_1=500~\Omega$ or equivalent $R_T=Z_{OUT}$ of pulse generator (typically 50 $\Omega)$

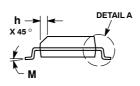
Figure 4. Test Circuit

PACKAGE DIMENSIONS

SOIC-14 NB CASE 751A-03 ISSUE K







- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

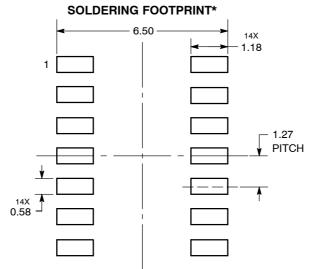
 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.

 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.

 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

| | MILLIN | IETERS | INC | HES |
|------------|--------|--------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 1.35 | 1.75 | 0.054 | 0.068 |
| A 1 | 0.10 | 0.25 | 0.004 | 0.010 |
| АЗ | 0.19 | 0.25 | 0.008 | 0.010 |
| b | 0.35 | 0.49 | 0.014 | 0.019 |
| D | 8.55 | 8.75 | 0.337 | 0.344 |
| Е | 3.80 | 4.00 | 0.150 | 0.157 |
| е | 1.27 | BSC | 0.050 | BSC |
| Н | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.019 |
| L | 0.40 | 1.25 | 0.016 | 0.049 |
| М | 0° | 7° | 0° | 7° |

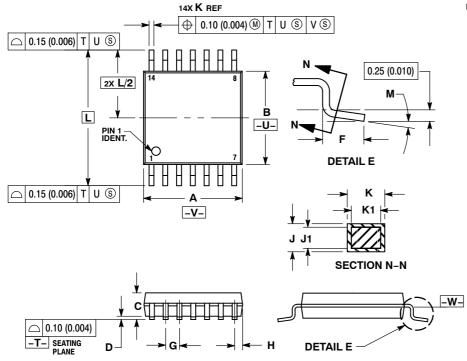


DIMENSIONS: MILLIMETERS

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TSSOP-14 CASE 948G-01 **ISSUE B**



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. CONDITION.
 6. TERMINAL NUMBERS ARE SHOWN FOR

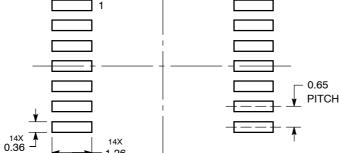
 - REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| | MILLIN | LIMETERS INCHES | | HES |
|-----|--------|-----------------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 4.90 | 5.10 | 0.193 | 0.200 |
| В | 4.30 | 4.50 | 0.169 | 0.177 |
| С | | 1.20 | | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 | BSC | 0.026 BSC | |
| Н | 0.50 | 0.60 | 0.020 | 0.024 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| Ĺ | 6.40 | BSC | 0.252 BSC | |
| М | 0 ° | 8 ° | 0 ° | 8 ° |



DIMENSIONS: MILLIMETERS



1.26

SOLDERING FOOTPRINT

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